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APPLICANTS

Dharam Pal Gosain, Tokyo, JAPAN;

Akio Machida, Kanagawa, JAPAN;

Kazushi Nakano, Tokyo, JAPAN; Toshio Fujino, Kanagawa, JAPAN;

Junichi Sato, Tokyo, JAPAN;

** CONTINUING DATA *****

** FOREIGN APPLICATIONS *****

JAPAN P2002-242614 08/22/2002

IF REQUIRED, FOREIGN FILING LICENSE GRANTED

** 04/21/2004

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 17	TOTAL CLAIMS 37	INDEPENDENT CLAIMS 4
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance	EXAMINER'S SIGNATURE <i>[Signature]</i>	INITIALS <i>[Initials]</i>		
Verified and Acknowledged				

ADDRESS

26263

SONNENSCHN NATH & ROSENTHAL LLP

P.O. BOX 061080

WACKER DRIVE STATION, SEARS TOWER

CHICAGO, IL

60606-1080

TITLE

Method of producing crystalline semiconductor material and method of fabricating semiconductor device

FILING FEE	FEES: Authority has been given in Paper	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of
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